NSN 5961-01-235-2204

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View Online at https://aerobasegroup.com/nsn/5961-01-235-2204
Inclosure Material:
Metal
Overall Length:
0.955 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case and quality assurance level s
Overall Width Across Flats:
0.437 inches
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 8.0 emitter to
base voltage, static, collector open
Current Rating Per Characteristic:
5.00 amperes source cutoff current and 0.50 amperes source cutoff current
Power Rating Per Characteristic:
30.0 watts small-signal input power, common-collector preset
Transfer Ratio:
80.0 static forward current transfer ratio, common-emitter and 240.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Thread Series Designator:
Unf
Terminal Type And Quantity:
3 tab, solder lug
Specification Data:
81349-mil-s-19500/374 government specification
Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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